## Serial-Input PLL Frequency Synthesizer with Analog Phase Detector Interfaces with Dual-Modulus Prescalers

The MC145159-1 has a programmable 14-bit reference counter, as well as fully programmable divide-by-N/divide-by-A counters. The counters are programmed serially through a common data input and latched into the appropriate counter latch, according to the last data bit (control bit) entered.

When combined with a loop filter and VCO, this device can provide all the remaining functions for a PLL frequency synthesizer operating up to the device's frequency limit. For higher VCO frequency operations, a down mixer or a dual-modulus prescaler can be used between the VCO and the PLL.

- Operating Temperature Range: - 40 to $85^{\circ} \mathrm{C}$
- Low Power Consumption Through Use of CMOS Technology
- 3.0 to 9.0 V Supply Range
- On- or Off-Chip Reference Oscillator Operation
- Compatible with the Serial Peripheral Interface (SPI) on CMOS MCUs
- $\div$ R Range $=3$ to 16383
- $\div$ N Range $=16$ to $1023, \div$ A Range $=0$ to 127
- High-Gain Analog Phase Detector
- See Application Note AN969


## PIN ASSIGNMENTS

PLASTIC DIP
AND SOG PACKAGE

*FSO is not and cannot be used as a digital phase detector output.

MAXIMUM RATINGS* (Voltages Referenced to $\mathrm{V}_{\mathrm{SS}}$ )

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | DC Supply Voltage | -0.5 to +10 | V |
| $\mathrm{~V}_{\text {in }}, \mathrm{V}_{\text {out }}$ | Input or Output Voltage (DC or Transient) | -0.5 to $\mathrm{V}_{\mathrm{DD}}+0.5$ | V |
| $\mathrm{I}_{\text {in }}, \mathrm{I}_{\text {out }}$ | Input or Output Current (DC or Transient), <br> per Pin | $\pm 10$ | mA |
| $\mathrm{I}_{\mathrm{DD}}, \mathrm{I}_{\mathrm{SS}}$ | Supply Current, $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\text {SS }}$ Pins | $\pm 30$ | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation, per Package | 500 | mW |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature (8-Second Soldering) | 260 | ${ }^{\circ} \mathrm{C}$ |

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation it is recommended that $V_{\text {in }}$ and $V_{\text {out }}$ be constrained to the range $\mathrm{V}_{\mathrm{SS}} \leq\left(\mathrm{V}_{\text {in }}\right.$ or $V_{\text {out }} \leq V_{\text {DD }}$.
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either $\mathrm{V}_{\mathrm{SS}}$ or $V_{D D}$ ).

* Maximum Ratings are those values beyond which damage to the device may occur.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to $\mathrm{V}_{\text {SS }}$ except $I_{C R}$ and $I_{\text {APD }}$ which are referenced to $\mathrm{V}_{\text {SS }}$ )

| Characteristic |  | Symbol | VDD | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  | $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min |  | Max | Min | Max | Min | Max |  |
| Power Supply Voltage Range |  |  | $V_{\text {DD }}$ | - | 3 | 9 | 3 | 9 | 3 | 9 | V |
| $\begin{aligned} & \text { Output Voltage } \\ & V_{\text {in }}=0 \mathrm{~V} \text { or } V_{\text {DD }} \\ & \mathrm{I}_{\text {out }}=0 \mu \mathrm{~A} \\ & \text { (Except OSC } \end{aligned}$ | 0 Level <br> 1 Level | $\mathrm{V}_{\mathrm{OL}}$ | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & \hline 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | - | $\begin{aligned} & \hline 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | - | $\begin{aligned} & \hline 0.05 \\ & 0.05 \\ & 0.05 \end{aligned}$ | V |
|  |  | $\mathrm{V}_{\mathrm{OH}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & \hline 2.95 \\ & 4.95 \\ & 8.95 \end{aligned}$ | - | $\begin{aligned} & \hline 2.95 \\ & 4.95 \\ & 8.95 \end{aligned}$ | - | $\begin{aligned} & 2.95 \\ & 4.95 \\ & 8.95 \end{aligned}$ | - |  |
| $\begin{aligned} & \hline \text { Output Voltage } \\ & \text { OSC }_{\text {out }} \\ & \mathrm{V}_{\text {in }}=0 \mathrm{~V} \text { or } \mathrm{V}_{\mathrm{DD}} \end{aligned}$ | 0 Level <br> 1 Level | $\mathrm{V}_{\text {OL }}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & \hline 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | - | $\begin{aligned} & \hline 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | - | $\begin{aligned} & 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | V |
|  |  | $\mathrm{V}_{\mathrm{OH}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - |  |
| $\Delta$ Voltage, $\mathrm{V}_{\mathrm{CH}}-\mathrm{V}_{\text {APDout, }}$, ${ }^{\text {APDDout }} \approx 0 \mu \mathrm{~A}$ |  | $\Delta \mathrm{V}$ | - | - | - | - | 1.05 | - | - | V |
| Input Voltage $\mathrm{V}_{\text {out }}=0.5 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}-0.5 \mathrm{~V}$ (All Outputs Except OSC ${ }_{\text {out }}$ ) | 0 Level <br> 1 Level | $\mathrm{V}_{\mathrm{IL}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & \hline 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | - | $\begin{aligned} & \hline 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | - | $\begin{aligned} & \hline 0.9 \\ & 1.5 \\ & 2.7 \end{aligned}$ | V |
|  |  | $\mathrm{V}_{\mathrm{IH}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - | $\begin{aligned} & 2.1 \\ & 3.5 \\ & 6.3 \end{aligned}$ | - |  |
| $\begin{array}{\|ll} \text { Input } \mathrm{Voltage} e^{*}-\mathrm{OSC} & \\ \mathrm{~V}_{\mathrm{in}}=2.1 \mathrm{~V} \text { or } 0.9 \mathrm{~V} & 0 \text { Level } \\ \mathrm{V}_{\mathrm{O}}=3.5 \mathrm{~V} \text { or } 1.5 \mathrm{~V} & \\ \mathrm{~V}_{\mathrm{O}}=6.3 \mathrm{~V} \text { or } 2.7 \mathrm{~V} & \\ & \\ & \\ \mathrm{~V}_{\mathrm{O}}=0.9 \mathrm{~V} \text { or } 2.1 \mathrm{~V} & \\ \mathrm{~V}_{\mathrm{O}}=1.5 \mathrm{~V} \text { or } 3.5 \mathrm{~V} & \\ \mathrm{~V}_{\mathrm{O}}=2.7 \mathrm{~V} \text { or } 6.3 \mathrm{~V} & \\ \hline \end{array}$ |  | $\mathrm{V}_{\mathrm{IL}}$ | 3 5 9 | - | 0 0 0 | - | 0 0 0 | - | 0 0 0 | V |
|  |  | $\mathrm{V}_{\mathrm{IH}}$ | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 3.0 \\ & 5.0 \\ & 9.0 \end{aligned}$ | - | $\begin{aligned} & 3.0 \\ & 5.0 \\ & 9.0 \end{aligned}$ | - | $\begin{aligned} & 3.0 \\ & 5.0 \\ & 9.0 \end{aligned}$ | - | V |
| $\begin{aligned} & \text { Output Current }-\mathrm{MC} \\ & \mathrm{~V}_{\text {out }}=2.7 \mathrm{~V} \\ & \mathrm{~V}_{\text {out }}=4.6 \mathrm{~V} \\ & \mathrm{~V}_{\text {out }}=8.5 \mathrm{~V} \end{aligned}$ | Source | IOH | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & -0.60 \\ & -0.90 \\ & -1.50 \end{aligned}$ | - | $\begin{aligned} & -0.50 \\ & -0.75 \\ & -1.25 \end{aligned}$ | - | $\begin{aligned} & -0.30 \\ & -0.50 \\ & -0.80 \end{aligned}$ | - | mA |
| $\begin{aligned} & V_{\text {out }}=0.3 \mathrm{~V} \\ & V_{\text {out }}=0.4 \mathrm{~V} \\ & V_{\text {out }}=0.5 \mathrm{~V} \end{aligned}$ | Sink | ${ }^{\text {IOL}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 1.30 \\ & 1.90 \\ & 3.80 \end{aligned}$ | - | $\begin{aligned} & \hline 1.10 \\ & 1.70 \\ & 3.30 \end{aligned}$ | - | $\begin{aligned} & 0.66 \\ & 1.08 \\ & 2.10 \end{aligned}$ | - |  |
| Output Current, $\mathrm{C}_{\mathrm{R}}, \mathrm{V}_{\mathrm{CR}}=4.5 \mathrm{~V}, \mathrm{R}_{\mathrm{R}}=240 \mathrm{k}$ |  | ICR | 9 | - | - | -90 | -110 | - | - | $\mu \mathrm{A}$ |
| $\begin{aligned} & \text { Output Current, APD } \\ & \mathrm{R}_{\mathrm{O}}=240 \mathrm{k}, \mathrm{~V}_{\mathrm{CH}}=0 \mathrm{~V}, \mathrm{~V}_{\text {APDout }}=4.5 \mathrm{~V} \end{aligned}$ |  | IAPD | 9 | - | - | 170 | 350 | - | - | $\mu \mathrm{A}$ |
| Output Current - Other Outputs  <br> $V_{\text {out }}=2.7 \mathrm{~V}$ Source <br> $V_{\text {out }}=4.6 \mathrm{~V}$  <br> $V_{\text {out }}=8.5 \mathrm{~V}$ Sink <br> $V_{\text {out }}=0.3 \mathrm{~V}$  <br> $V_{\text {out }}=0.4 \mathrm{~V}$  <br> $\mathrm{~V}_{\text {out }}=0.5 \mathrm{~V}$  |  | IOH | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & -0.44 \\ & -0.64 \\ & -1.30 \end{aligned}$ | - | $\left\lvert\, \begin{aligned} & -0.35 \\ & -0.51 \\ & -1.00 \end{aligned}\right.$ | - | $\begin{aligned} & -0.22 \\ & -0.36 \\ & -0.70 \end{aligned}$ | - | mA |
|  |  | ${ }^{\text {IOL}}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 0.44 \\ & 0.64 \\ & 1.30 \end{aligned}$ | - | $\begin{aligned} & \hline 0.35 \\ & 0.51 \\ & 1.00 \end{aligned}$ | - | $\begin{aligned} & 0.22 \\ & 0.36 \\ & 0.70 \end{aligned}$ | - |  |
| Input Current - Data, CLK, ENB |  | 1 in | 9 | - | $\pm 0.3$ | - | $\pm 0.1$ | - | $\pm 1.0$ | $\mu \mathrm{A}$ |
| Input Current - $\mathrm{f}_{\text {in }}$, OSC $_{\text {in }}$ |  | 1 in | 9 | $\pm 2$ | $\pm 50$ | $\pm 2$ | $\pm 25$ | $\pm 2$ | $\pm 22$ | $\mu \mathrm{A}$ |
| Input Capacitance |  | $\mathrm{C}_{\text {in }}$ | - | - | 10 | - | 10 | - | 10 | pF |
| Three-State Output Capacitance - FSO |  | $\mathrm{C}_{\text {out }}$ | - | - | 10 | - | 10 | - | 10 | pF |
| Quiescent Current $\mathrm{V}_{\text {in }}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{DD}}$ $l_{\text {out }}=0 \mu \mathrm{~A}$ |  | IDD | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{gathered} \hline 800 \\ 1200 \\ 1600 \end{gathered}$ | - | $\begin{aligned} & \hline 800 \\ & 1200 \\ & 1600 \end{aligned}$ | - | $\begin{aligned} & 1600 \\ & 2400 \\ & 3200 \end{aligned}$ | $\mu \mathrm{A}$ |
| Three-State Leakage Current, $\mathrm{V}_{\text {out }}=0 \mathrm{~V}$ or 9 V |  | IOZ | 9 | - | $\pm 0.3$ | - | $\pm 0.1$ | - | $\pm 3.0$ | $\mu \mathrm{A}$ |

*dc coupled square wave.

SWITCHING CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}\right)$

| Characteristic | Figure No. | Symbol | VDD | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Rise Time - MC | 4, 9 | t'LH | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & 115 \\ & 60 \\ & 40 \end{aligned}$ | ns |
| Output Fall Time - MC | 4, 9 | tTHL | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & 60 \\ & 34 \\ & 30 \end{aligned}$ | ns |
| Output Rise and Fall Time - LD and $\mathrm{SR}_{\text {out }}$ | 4, 9 | $\begin{aligned} & \text { tTLH, } \\ & \text { tTHL } \end{aligned}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & 140 \\ & 80 \\ & 60 \end{aligned}$ | ns |
| Propagation Delay Time - $\mathrm{fin}_{\text {in }}$ to MC | 5, 9 | $\begin{aligned} & \hline \text { tPLH, } \\ & \text { tPHL } \end{aligned}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | - | $\begin{aligned} & \hline 125 \\ & 80 \\ & 50 \end{aligned}$ | ns |
| Setup Times - Data to CLK <br> CLK to ENB | 6 | $t_{\text {su }}$ | $\begin{aligned} & 3 \\ & 5 \\ & 9 \\ & \hline 3 \\ & \hline 5 \\ & 9 \end{aligned}$ | 30 20 18 70 32 25 | - - - - - | ns |
| Hold Time - CLK to Data | 6 | $t_{\text {h }}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 12 \\ & 12 \\ & 15 \end{aligned}$ | - | ns |
| Recovery Time - ENB to CLK | 6 | trec | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{gathered} \hline 5 \\ 10 \\ 20 \end{gathered}$ | - | ns |
| Input Rise and Fall Times - CLK, OSC ${ }_{\text {in }}$, $\mathrm{f}_{\text {in }}$ | 7 | $\mathrm{tr}_{\mathrm{r}} \mathrm{tf}$ | $\begin{aligned} & 3 \\ & 5 \\ & 9 \end{aligned}$ | 二 | $\begin{gathered} 5 \\ 2 \\ 0.5 \end{gathered}$ | $\mu \mathrm{s}$ |
| Input Pulse Width - ENB and CLK | 8 | $t_{w}$ | $\begin{aligned} & \hline 3 \\ & 5 \\ & 9 \end{aligned}$ | $\begin{aligned} & 40 \\ & 35 \\ & 25 \end{aligned}$ | - | ns |

NOTE: Refer to the graphs and text in application note AN969 for maximum frequency information.

## PIN DESCRIPTIONS

## INPUT PINS

OSC $_{\text {in }}$, OSC ${ }_{\text {out }}$
Oscillator Input and Oscillator Output (PDIP, SOG Pins 2, 3; SSOP - Pins 7, 8)

These pins form an on-chip reference oscillator when connected to terminals of an external parallel-resonant crystal. Frequency-setting capacitors of appropriate value must be connected from OSC in to $\mathrm{V}_{\mathrm{SS}}$ and OSC $\mathrm{O}_{\text {out }}$ to $\mathrm{V}_{\text {SS }}$. OSC $\mathrm{in}_{\text {m }}$ may also serve as input for an externally-generated reference signal. This signal will typically be ac coupled to OSC $_{\mathrm{in}}$, but for larger amplitude signals (standard CMOS logic levels), dc coupling may also be used. In the external reference mode, no connection is required to OSC out.
$f_{\text {in }}$
Frequency Input (PDIP, SOG - Pin 10, SSOP - Pin 15)
Input to the positive edge triggered divide-by-N and di-vide-by-A counters. $f_{i n}$ is typically derived from a dualmodulus prescaler and is ac coupled. This input has an inverter biased in the linear region to allow use with ac coupled signals as low as 500 mV peak-to-peak or direct coupled signals swinging from $\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{SS}}$.

## DATA

Serial Data Input (PDIP, SOG - Pin 12, SSOP - Pin 17)
Counter and control information is shifted into this input. The last data bit entered goes into the one-bit control shift register. A logic 1 allows the reference counter information to be loaded into its 14 -bit latch when ENB goes high. A logic 0 entered as the control bit disables the reference counter latch. The divide-by-A/divide-by-N counter latch is loaded, regardless of the contents of the control register, when ENB goes high. The data entry format is shown in Figure 1.

## ENB

Transparent Latch Enable (PDIP, SOG - Pin 13, SSOP - Pin 18)

A logic high on this input allows data to be entered into the divide-by-A/divide-by-N latch and, if the control bit is high, into the reference counter latch. Counter programming is unaffected when ENB is low. ENB should be kept normally low and pulsed high to transfer data to the latches.

CLK
Shift Register Clock (PDIP, SOG - Pin 11, SSOP - Pin 16)
A low-to-high transition on this input shifts data from the serial data input into the shift registers.

## COMPONENT PINS

## $C_{R}$

Ramp Capacitor (PDIP, SOG - Pin 15, SSOP - Pin 20)
The capacitor connected from this pin to $\mathrm{V}_{\mathrm{SS}}{ }^{\prime}$ is charged linearly, at a rate determined by $R_{R}$. The voltage on this capacitor is proportional to the phase difference of the frequencies present at the internal phase detector inputs. A polystyrene or mylar capacitor is recommended.

## $R_{R}$ <br> Ramp Current Bias Resistor (PDIP, SOG - Pin 20, SSOP - Pin 5)

A resistor connected from this pin to VSS' determines the rate at which the ramp capacitor is charged, thereby affecting the phase detector gain (see Figure 2).

## CH <br> Hold Capacitor (PDIP, SOG - Pin 18, SSOP - Pin 3)

The charge stored on the ramp capacitor is transferred to the capacitor connected from this pin to either $\mathrm{V}_{D D^{\prime}}$ or $\mathrm{V}_{\mathrm{SS}}$. The ratio of $C_{R}$ to $C_{H}$ should be large enough to have no effect on the phase detector gain $\left(C_{R}>10 C_{H}\right)$. A low-leakage capacitor should be used.

## Ro

Output Bias Current Resistor (PDIP, SOG - Pin 1, SSOP - Pin 6)

A resistor connected from this pin to $\mathrm{V}_{\text {SS }}$ biases the output N -Channel transistor, thereby setting a current sink on the analog phase detector output. This resistor adjusts the APD out bias current (see Figure 3).

## OUTPUT PINS

## APD out

Analog Phase Detector Output (PDIP, SOG - Pin 17, SSOP - Pin 2)

This output produces a voltage that controls an external VCO . The voltage range of this output ( V DD $=+9 \mathrm{~V}$ ) is from below +0.5 V to +8 V or more. The source impedance of this output is the equivalent of a source follower with an externally variable source resistor. The source resistor depends upon the output bias current controlled by the output bias current resistor, RO. The bias current is adjustable from 0.01 mA to 0.5 mA . The output voltage is not more than 1.05 V below the sampled point on the ramp. With a constant sample of the ramp voltage at 9 V and the hold capacitor of 50 pF , the instantaneous output ripple is about 5 mV peak-to-peak.


Figure 1. Data Entry Format

## CHARGE

Ramp Charge Indicator (PDIP, SOG - Pin 4, SSOP - Pin 9)
This output is high from the time $f_{R}$ goes high to the time fV goes high ( $\mathrm{f} R$ and fV are the frequencies at the phase detector inputs). This high voltage indicates that the ramp capacitor, $\mathrm{C}_{\mathrm{R}}$, is being charged.

## FSO

Three-State Frequency Steering Output (PDIP, SOG Pin 6, SSOP - Pin 11)

If the counted down input frequency on $f_{i n}$ is higher than the counted down reference frequency of $\mathrm{OSC}_{\mathrm{in}}$, this output goes low. If the counted down VCO frequency is lower than that of the counted down $\mathrm{OSC}_{\mathrm{in}}$, this output goes high.

The repetition rate of the frequency steering output pulses is approximately equal to the difference of the frequencies of the two counted down inputs from the VCO and OSC $\mathrm{O}_{\mathrm{in}}$. See Application Note AN969 for further information.

## LD

Lock Detector Indicator (PDIP, SOG - Pin 9, SSOP Pin 14)

This output is high during lock and goes low to indicate a non-lock condition. The frequency and duration of the nonlock pulses will be the same as either polarity of the frequency steering output.

## MC <br> Dual Modulus Prescaler Control (PDIP, SOG - Pin 8, SSOP - Pin 13)

The modulus control level is low at the beginning of a count cycle and remains low until the divide-by-A counter has counted down from its programmed value. At that time, the modulus control goes high and remains high until the di-vide-by-N counter has counted the rest of the way down from its programmed value ( $\mathrm{N}-\mathrm{A}$ additional counts since both divide-by- N and divide-by-A are counting down during the first portion of the cycle). Modulus control is then set back low, the counters preset to their respective programmed values, and the above sequence repeated. This provides for a total programmable divide value of $N_{T}=N \cdot P+A$, where $P$
and $P+1$ represent the dual modulus prescaler divide values respectively for high and low modulus control levels, $N$ is the number programmed into the divide-by-N counter, and $A$ is the number programmed into the divide-by-A counter.

## $\mathbf{S R}_{\text {out }}$

Shift Register Output (PDIP, SOG - Pin 14, SSOP - Pin 19)
This pin is the non-inverted output of the last stage of the 32-bit serial data shift register. It is not latched by the ENB line. If unused, $\mathrm{SR}_{\text {out }}$ should be floated.

## POWER SUPPLY

## VDD

Positive Power Supply (PDIP, SOG - Pin 5, SSOP - Pin 10)
Positive power supply input for all sections of the device except the analog phase detector. VDD and VDD' should be powered up at the same time to avoid damage to the MC145159-1. VDD must be tied to the same potential as $V_{D D}$.

## vss

Negative Power Supply (PDIP, SOG - Pin 7, SSOP - Pin 12)
Circuit ground for all sections of the MC145159-1 except the analog phase detector. $V_{S S}$ must be tied to the same potential as $\mathrm{V}_{\mathrm{SS}}{ }^{\prime}$.

## VSS' <br> Analog Phase Detector Circuit Ground (PDIP, SOG Pin 16, SSOP - Pin 1)

Separate power supply and ground inputs are provided to help reduce the effects in the analog section of noise coming from the digital sections of this device and the surrounding circuitry.

## VDD'

Analog Power Supply (PDIP, SOG - Pin 19, SSOP - Pin 4)
Separate power supply and ground inputs are provided to help reduce the effects in the analog section of noise coming from the digital sections of this device and the surrounding circuitry.


Figure 2. Charge Current vs Ramp Resistance


Figure 3. APD out Bias Current vs Output Resistance

DESIGN EQUATION

$$
\mathrm{K}_{\phi}=\frac{\mathrm{ICHARGE}}{2 \pi \mathrm{f}_{\mathrm{R}} \mathrm{C}_{\mathrm{R}}}
$$

where
$\mathrm{K}_{\phi}=$ phase detector gain, ICHARGE is from Figure 2
$f_{R}=$ reference frequency
$\mathrm{C}_{\mathrm{R}}=$ ramp capacitor (in farads)

## SWITCHING WAVEFORMS



Figure 4.


Figure 6.


Figure 8.


Figure 5.


Figure 7.


* Includes all probe and fixture capacitance.

Figure 9. Test Circuit

## DESIGN CONSIDERATIONS

## CRYSTAL OSCILLATOR CONSIDERATIONS

The following options may be considered to provide a reference frequency to Motorola's CMOS frequency synthesizers.

## Use of a Hybrid Crystal Oscillator

Commercially available temperature-compensated crystal oscillators (TCXOs) or crystal-controlled data clock oscillators provide very stable reference frequencies. An oscillator capable of sinking and sourcing $50 \mu \mathrm{~A}$ at CMOS logic levels may be direct or dc coupled to $\mathrm{OSC}_{\mathrm{in}}$. In general, the highest frequency capability is obtained utilizing a direct coupled square wave having a rail-to-rail ( $\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{SS}}$ ) voltage swing. If the oscillator does not have CMOS logic levels on the outputs, capacitive or ac coupling to OSC in may be used. OSC out $^{\text {, an unbuffered output, should be left floating. }}$

For additional information about TCXOs and data clock oscillators, please consult the latest version of the eem Electronic Engineers Master Catalog, the Gold Book, or similar publications.

## Design an Off-Chip Reference

The user may design an off-chip crystal oscillator using ICs specifically developed for crystal oscillator applications, such as the MC12061 MECL device. The reference signal from the MECL device is ac coupled to OSC in. For large amplitude signals (standard CMOS logic levels), dc coupling is used. OSC ${ }_{\text {out }}$, an unbuffered output, should be left floating. In general, the highest frequency capability is obtained with a direct-coupled square wave having rail-to-rail voltage swing.

## Use of the On-Chip Oscillator Circuitry

The on-chip amplifier (a digital inverter) along with an appropriate crystal may be used to provide a reference source frequency. A fundamental mode crystal, parallel resonant at the desired operating frequency, should be connected as shown in Figure 10.

For $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$, the crystal should be specified for a loading capacitance, $\mathrm{CL}_{\mathrm{L}}$, which does not exceed 32 pF for frequencies to approximately $8 \mathrm{MHz}, 20 \mathrm{pF}$ for frequencies in the area of 8 to 15 MHz , and 10 pF for higher frequencies. These are guidelines that provide a reasonable compromise between IC capacitance, drive capability, swamping variations in stray and IC input/output capacitance, and realistic $C_{L}$ values. Assuming R1 = $0 \Omega$. the shunt load capacitance, $C_{L}$, presented across the crystal can be estimated to be:

$$
\mathrm{C}_{\mathrm{L}}=\frac{\mathrm{C}_{\text {in }} \mathrm{C}_{\text {out }}}{\mathrm{C}_{\text {in }}+\mathrm{C}_{\text {out }}}+\mathrm{C}_{\mathrm{a}}+\mathrm{C}_{\text {stray }}+\frac{\mathrm{C} 1 \cdot \mathrm{C}_{2}}{\mathrm{C}_{1}+\mathrm{C} 2}
$$

where

$$
\mathrm{C}_{\mathrm{in}}=5 \mathrm{pF} \text { (see Figure 11) }
$$

$C_{\text {out }}=6 \mathrm{pF}$ (see Figure 11)
$\mathrm{C}_{\mathrm{a}}=1 \mathrm{pF}$ (see Figure 11)
C1 and C2 = external capacitors (see Figure 10)
$\mathrm{C}_{\text {stray }}=$ the total equivalent external circuit stray capacitance appearing across the crystal terminals
The oscillator can be "trimmed" on-frequency by making a portion or all of C1 variable. The crystal and associated components must be located as close as possible to the OSC in and OSC ${ }_{\text {out }}$ pins to minimize distortion, stray capacitance,
stray inductance, and start-up stabilization time. Circuit stray capacitance can also be handled by adding the appropriate stray value to the values for $\mathrm{C}_{\mathrm{in}}$ and $\mathrm{C}_{\text {out }}$. For this approach, the term $\mathrm{C}_{\text {stray }}$ becomes zero in the above expression for $\mathrm{C}_{\mathrm{L}}$.

Power is dissipated in the effective series resistance of the crystal, $R_{e}$, in Figure 12. The maximum drive level specified by the crystal manufacturer represents the maximum stress that a crystal can withstand without damaging or excessive shift in operating frequency. R1 in Figure 10 limits the drive level. The use of R1 is not necessary in most cases.

To verify that the maximum dc supply voltage does not overdrive the crystal, monitor the output frequency as a function of voltage at OSC ${ }_{\text {out }}$. (Care should be taken to minimize loading.) The frequency should increase very slightly as the dc supply voltage is increased. An overdriven crystal will decrease in frequency or become unstable with an increase in supply voltage. The operating supply voltage must be reduced or R1 must be increased in value if the overdriven condition exists. The user should note that the oscillator start-up time is proportional to the value of R1.

Through the process of supplying crystals for use with CMOS inverters, many crystal manufacturers have developed expertise in CMOS oscillator design with crystals. Discussions with such manufacturers can prove very helpful. See Table 1.


* May be deleted in certain cases. See text.

Figure 10. Pierce Crystal Oscillator Circuit


Figure 11. Parasitic Capacitances of the Amplifier and $C_{\text {stray }}$


NOTE: Values are supplied by crystal manufacturer (parallel resonant crystal).

Figure 12. Equivalent Crystal Networks

Table 1. Partial List of Crystal Manufacturers

| Name | Address | Phone |
| :--- | :--- | :---: |
| United States Crystal Corp. | 3605 McCart Ave., Ft. Worth, TX 76110 | (817) 921-3013 |
| Crystek Crystal | 2351 Crystal Dr., Ft. Myers, FL 33907 | (813) 936-2109 |
| Statek Corp. | 512 N. Main St., Orange, CA 92668 | (714) 639-7810 |

NOTE: Motorola cannot recommend one supplier over another and in no way suggests that this is a complete listing of crystal manufacturers.

## RECOMMENDED READING

Technical Note TN-24, Statek Corp.
Technical Note TN-7, Statek Corp.
E. Hafner, "The Piezoelectric Crystal Unit - Definitions and Method of Measurement", Proc. IEEE, Vol. 57, No. 2 Feb., 1969.
D. Kemper, L. Rosine, "Quartz Crystals for Frequency

Control", Electro-Technology, June, 1969.
P. J. Ottowitz, "A Guide to Crystal Selection", Electronic Design, May, 1966.
D. Babin, "Designing Crystal Oscillators", Machine Design, March 7, 1985.
D. Babin, "Guidelines for Crystal Oscillator Design", Machine Design, April 25, 1985.


Figure 13. Timing Diagram for Minimum Divide Value ( $\mathrm{N}=16$ )

## PACKAGE DIMENSIONS

P SUFFIX
PLASTIC DIP (DUAL IN-LINE PACKAGE)
CASE 738-03


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLNG DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE
MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE
DAMBAR PROTRUSION. ALLOWABLE
DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | ---: | ---: | ---: | ---: |
|  | MIN |  | MAX | MIN |
| A | 12.65 | 12.95 | 0.499 | 0.510 |
| B | 7.40 | 7.60 | 0.292 | 0.299 |
| C | 2.35 | 2.65 | 0.093 | 0.104 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.50 | 0.90 | 0.020 |  |
| G | 1.27 BSC |  | 0.035 |  |
| J | 0.25 | 0.32 | 0.010 |  |
| K | 0.10 | 0.25 | 0.004 | 0.012 |
| M | $0^{\circ}$ | $7^{\circ}$ | 0.009 |  |
| P | 10.05 | 10.55 | 0.395 | $7^{\circ}$ |
| R | 0.25 | 0.75 | 0.415 |  |

## PLACE WHEN GET CASE\#

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (M) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

## How to reach us:

USA/EUROPE: Motorola Literature Distribution;
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki,
6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609
INTERNET: http://Design-NET.com
HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

